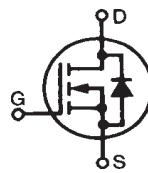


**Linear™ Power  
MOSFET w/ Extended  
FBSOA**

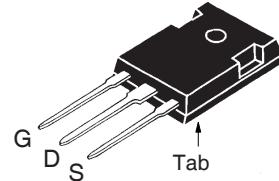
N-Channel Enhancement Mode  
Avalanche Rated

**IXTH12N100L**

**$V_{DSS}$  = 1000V  
 $I_{D25}$  = 12A  
 $R_{DS(on)}$  ≤ 1.3Ω**



**TO-247**



G = Gate      D = Drain  
 S = Source      Tab = Drain

| Symbol        | Test Conditions  | Maximum Ratings |           |
|---------------|--|-----------------|-----------|
| $V_{DSS}$     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                              | 1000            | V         |
| $V_{DGR}$     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GS} = 1\text{M}\Omega$ | 1000            | V         |
| $V_{GSS}$     | Continuous   | ±30             | V         |
| $V_{GSM}$     | Transient  | ±40             | V         |
| $I_{D25}$     | $T_c = 25^\circ\text{C}$   | 12              | A         |
| $I_{DM}$      | $T_c = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$                   | 25              | A         |
| $I_A$         | $T_c = 25^\circ\text{C}$   | 12              | A         |
| $E_{AS}$      | $T_c = 25^\circ\text{C}$   | 1.5             | J         |
| $P_D$         | $T_c = 25^\circ\text{C}$   | 400             | W         |
| $T_J$         |  | -55...+150      | °C        |
| $T_{JM}$      |  | 150             | °C        |
| $T_{stg}$     |  | -55...+150      | °C        |
| $T_L$         | 1.6mm (0.063 in.) from Case for 10s  | 300             | °C        |
| $T_{SOLD}$    | Plastic Body for 10s   | 260             | °C        |
| $M_d$         | Mounting Torque  | 1.13/10         | Nm/lb.in. |
| <b>Weight</b> |  | 6               | g         |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified) | Characteristic Values |      |                                       |
|--------------|---|-----------------------|------|---------------------------------------|
|              |   | Min.                  | Typ. | Max.                                  |
| $BV_{DSS}$   | $V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$                               | 1000                  |      | V                                     |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250\mu\text{A}$                                  | 3.5                   |      | 5.5 V                                 |
| $I_{GSS}$    | $V_{GS} = \pm 30\text{V}$ , $V_{DS} = 0\text{V}$                            |                       |      | ±100 nA                               |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0\text{V}$<br>$T_J = 125^\circ\text{C}$      |                       |      | 50 $\mu\text{A}$<br>500 $\mu\text{A}$ |
| $R_{DS(on)}$ | $V_{GS} = 20\text{V}$ , $I_D = 0.5 \cdot I_{DSS}$ , Note 1                  |                       | 1.3  | Ω                                     |

**Features**

- International Standard Package
- Designed for Linear Operation
- Avalanche Rated
- Molding Epoxy Meets UL94 V-0 Flammability Classification

**Advantages**

- Easy to Mount
- Space Savings
- High Power Density

**Applications**

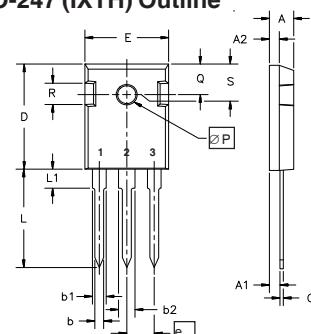
- Programmable Loads
- Current Regulators
- DC-DC Converters
- Battery Chargers
- DC Choppers
- Temperature and Lighting Controls

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)  | Characteristic Values |      |                           |
|--------------|--|-----------------------|------|---------------------------|
|              |  | Min.                  | Typ. | Max.                      |
| $g_{fs}$     | $V_{DS} = 20\text{V}$ , $I_D = 0.5 \cdot I_{DSS}$ , Note 1   | 3.0                   | 5.0  | S                         |
| $C_{iss}$    |  | 2500                  |      | pF                        |
| $C_{oss}$    |  | 300                   |      | pF                        |
| $C_{rss}$    |  | 95                    |      | pF                        |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 15\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{DSS}$<br>$R_G = 4.7\Omega$ (External) | 30                    |      | ns                        |
| $t_r$        |  | 55                    |      | ns                        |
| $t_{d(off)}$ |  | 110                   |      | ns                        |
| $t_f$        |  | 65                    |      | ns                        |
| $Q_{g(on)}$  |  | 155                   |      | nC                        |
| $Q_{gs}$     |  | 35                    |      | nC                        |
| $Q_{gd}$     |  | 55                    |      | nC                        |
| $R_{thJC}$   |  |                       | 0.31 | $^\circ\text{C}/\text{W}$ |
| $R_{thCS}$   |  | 0.21                  |      | $^\circ\text{C}/\text{W}$ |

### Safe-Operating-Area Specification

| Symbol | Test Conditions  | Characteristic Values |      |      |
|--------|--|-----------------------|------|------|
|        |  | Min.                  | Typ. | Max. |
| SOA    | $V_{DS} = 800\text{V}$ , $I_D = 0.25\text{A}$ , $T_C = 60^\circ\text{C}$ | 200                   |      | W    |

### TO-247 (IXTH) Outline



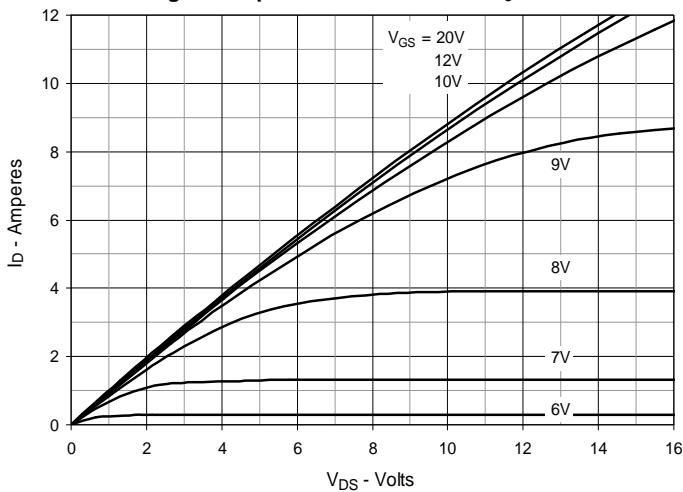
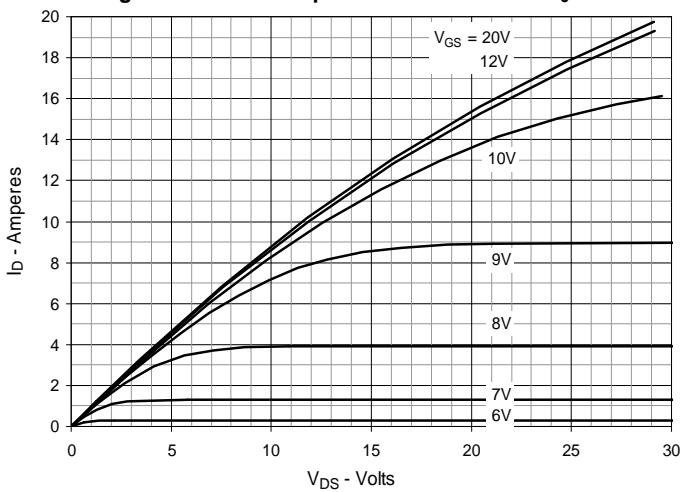
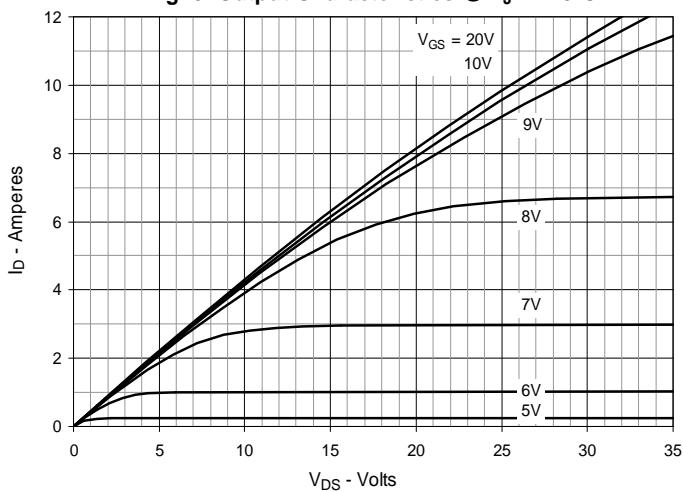
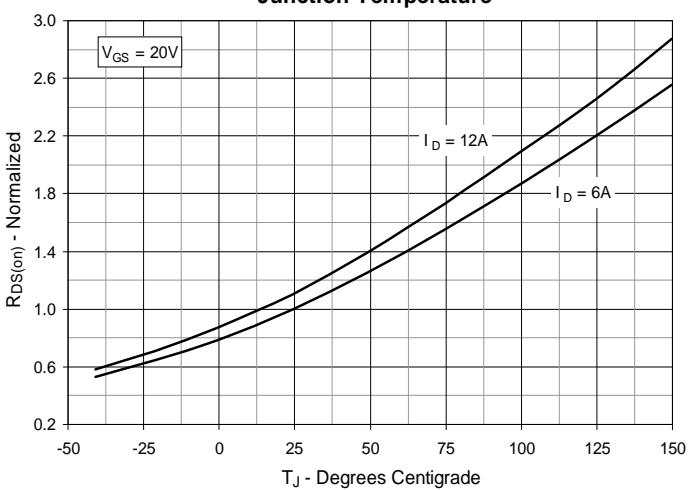
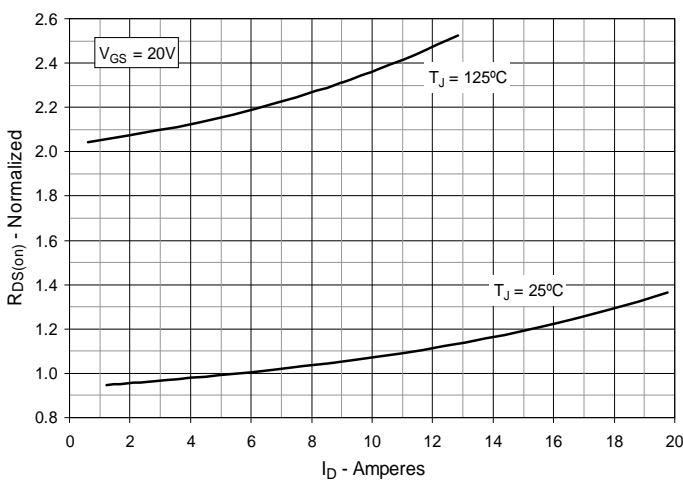
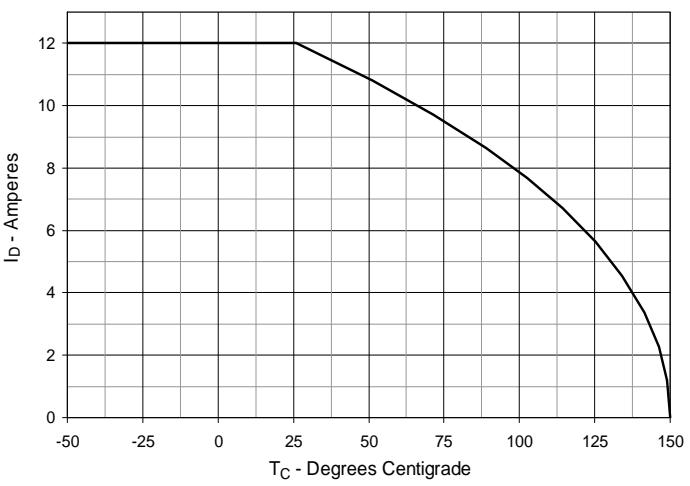
Terminals: 1 - Gate  
2 - Drain  
3 - Source

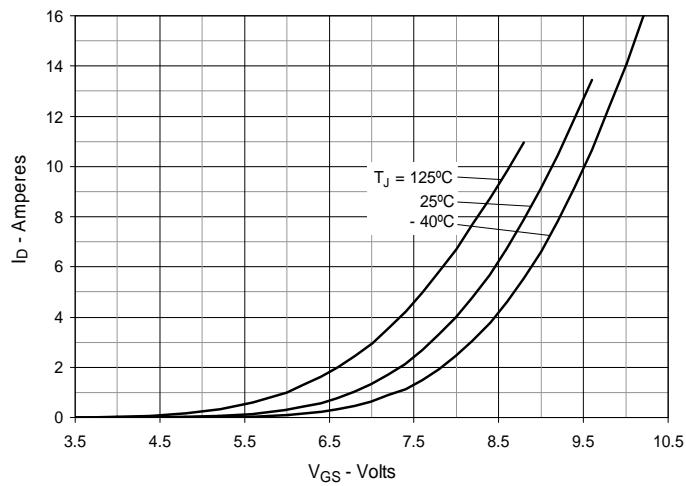
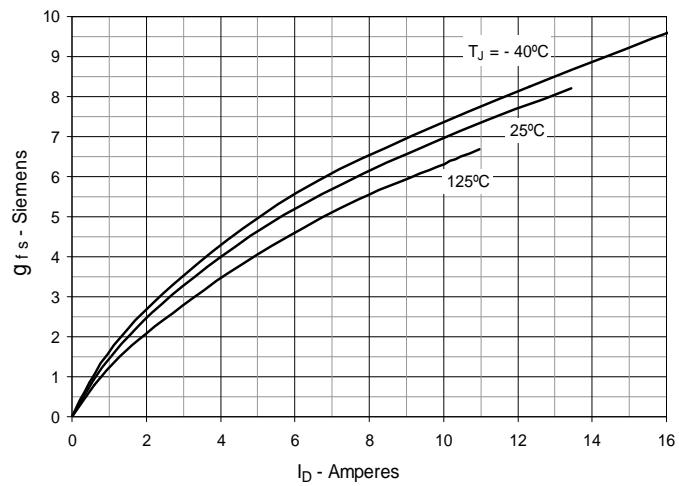
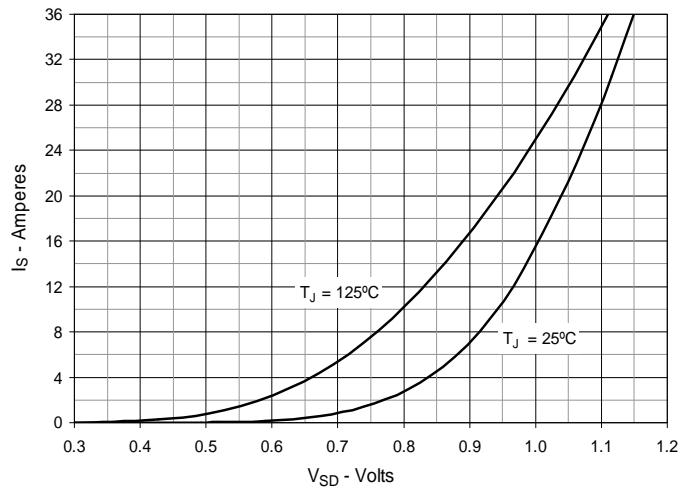
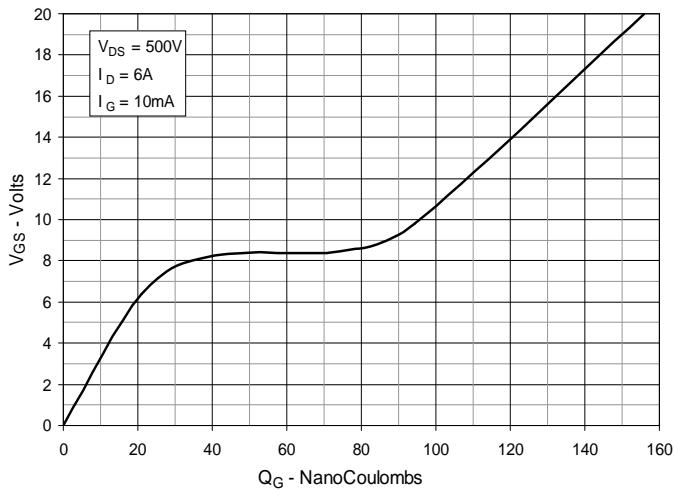
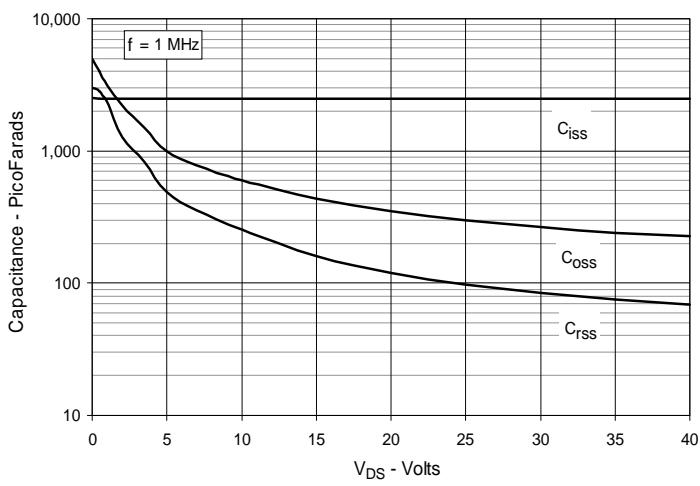
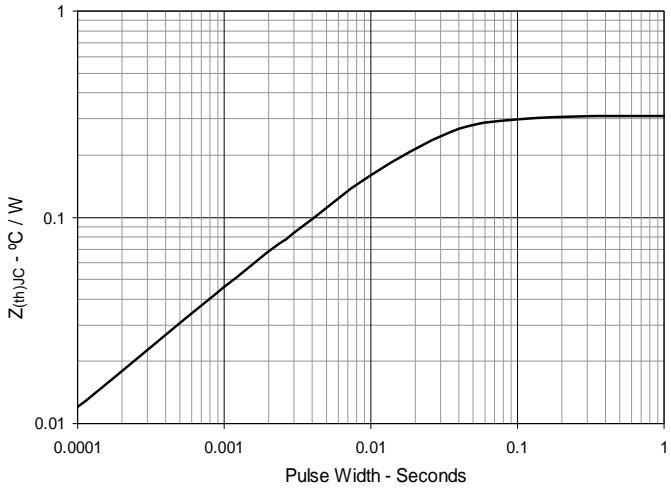
| Dim.           | Millimeter<br>Min. Max. | Inches<br>Min. Max. |
|----------------|-------------------------|---------------------|
| A              | 4.7 .5.3                | .185 .209           |
| A <sub>1</sub> | 2.2 2.54                | .087 .102           |
| A <sub>2</sub> | 2.2 2.6                 | .059 .098           |
| b              | 1.0 1.4                 | .040 .055           |
| b <sub>1</sub> | 1.65 2.13               | .065 .084           |
| b <sub>2</sub> | 2.87 3.12               | .113 .123           |
| C              | .4 .8                   | .016 .031           |
| D              | 20.80 21.46             | .819 .845           |
| E              | 15.75 16.26             | .610 .640           |
| e              | 5.20 5.72               | 0.205 0.225         |
| L              | 19.81 20.32             | .780 .800           |
| L1             | 4.50                    | .177                |
| ØP             | 3.55 3.65               | .140 .144           |
| Q              | 5.89 6.40               | 0.232 0.252         |
| R              | 4.32 5.49               | .170 .216           |
| S              | 6.15 BSC                | 242 BSC             |

### Source-Drain Diode

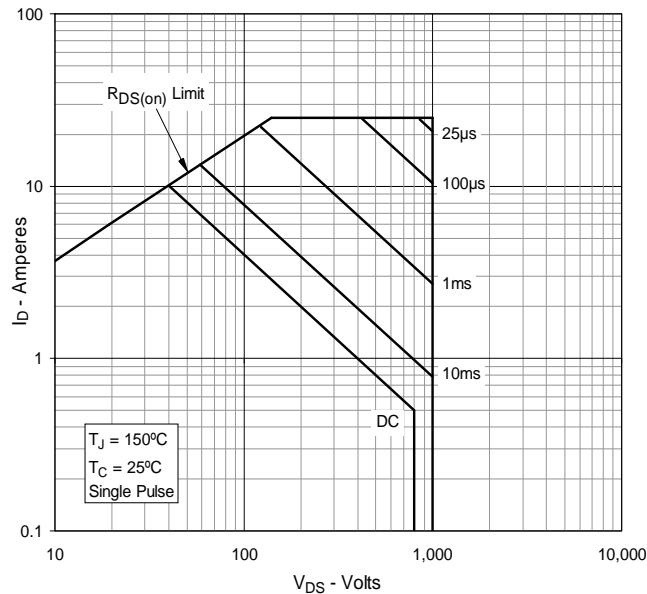
| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                   | Characteristic Values |      |      |
|----------|---|-----------------------|------|------|
|          |   | Min.                  | Typ. | Max. |
| $I_s$    | $V_{GS} = 0\text{V}$  |                       | 12   | A    |
| $I_{sm}$ | Repetitive, Pulse Width Limited by $T_{JM}$   |                       | 48   | A    |
| $V_{SD}$ | $I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1   |                       | 1.5  | V    |
| $t_{rr}$ | $I_F = I_S$ , $-di/dt = 100\text{A}/\mu\text{s}$ , $V_R = 100\text{V}$ , $V_{GS} = 0\text{V}$ | 1000                  |      | ns   |

Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

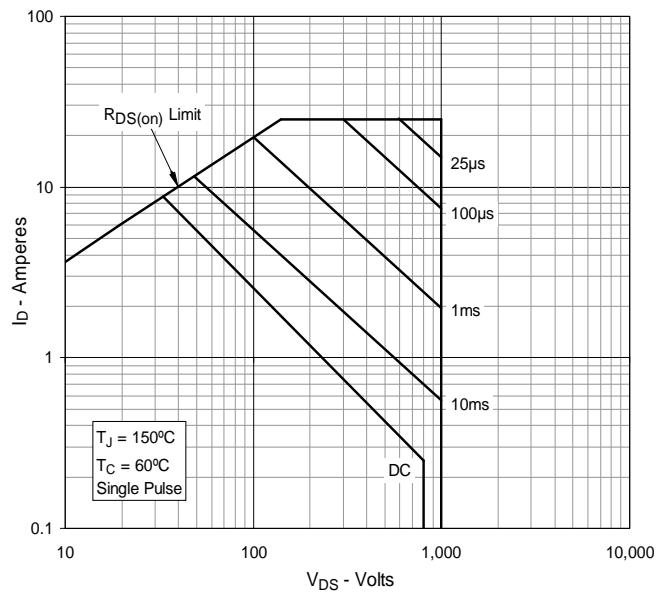
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** **Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 6\text{A}$  Value vs. Junction Temperature****Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 6\text{A}$  Value vs. Drain Current****Fig. 6. Maximum Drain Current vs. Case Temperature**

**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Forward Voltage Drop of Intrinsic Diode****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Maximum Transient Thermal Impedance**

**Fig. 13. Forward-Bias Safe Operating Area  
@  $T_C = 25^\circ\text{C}$**



**Fig. 14. Forward-Bias Safe Operating Area  
@  $T_C = 60^\circ\text{C}$**



# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [MOSFET](#) category:*

*Click to view products by [IXYS](#) manufacturer:*

Other Similar products are found below :

[614233C](#) [648584F](#) [IRFD120](#) [JANTX2N5237](#) [FCA20N60\\_F109](#) [FDZ595PZ](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [TPCC8103,L1Q\(CM](#)  
[MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [SSM6J414TU,LF\(T](#) [751625C](#) [BUK954R8-60E](#) [NTE6400](#) [SQJ402EP-](#)  
[T1-GE3](#) [2SK2614\(TE16L1,Q\)](#) [2N7002KW-FAI](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [ECH8691-TL-W](#) [FCAB21350L1](#) [P85W28HP2F-](#)  
[7071](#) [DMN1053UCP4-7](#) [NTE221](#) [NTE222](#) [NTE2384](#) [NTE2903](#) [NTE2941](#) [NTE2945](#) [NTE2946](#) [NTE2960](#) [NTE2967](#) [NTE2969](#) [NTE2976](#)  
[NTE6400A](#) [NTE2910](#) [NTE2916](#) [NTE2956](#) [NTE2911](#) [DMN2080UCB4-7](#) [TK10A80W,S4X\(S](#) [SSM6P69NU,LF](#) [DMP22D4UFO-7B](#)  
[DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)